TOSHIBA Photocoupler GaAlAs Ired & Photo-IC

TLP250

Transistor Inverter
Inverter For Air Conditionor
IGBT Gate Drive
Power MOS FET Gate Drive

The TOSHIBA TLP250 consists of a GaAlAs light emitting diode and a integrated photodetector.

This unit is 8-lead DIP package.

TLP250 is suitable for gate driving circuit of IGBT or power MOS FET.

- Input threshold current: IF=5mA(max.)
- Supply current (ICC): 11mA(max.)
- Supply voltage (V_{CC}): 10–35V
- Output current (I_O): ±1.5A (max.)
- Switching time (t_{pLH}/t_{pHL}): 1.5µs(max.)
- Isolation voltage: 2500V_{rms}(min.)
- UL recognized: UL1577, file No.E67349
- Option (D4) type

VDE approved: DIN VDE0884/06.92, certificate No.76823

Maximum operating insulation voltage: 630VPK

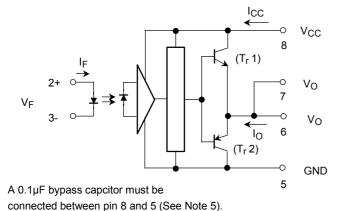
Highest permissible over voltage: 4000VPK

(Note) When a VDE0884 approved type is needed, please designate the "option (D4)"

• Creepage distance: 6.4mm(min.)

Clearance: 6.4mm(min.)

Schmatic

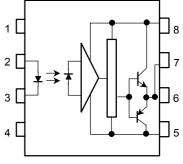


Truth Table

		Tr1	Tr2
Input LED	On	On	Off
	Off	Off	On

Weight: 0.54 g

Pin Configuration (top view)



- 1 : N.C.
- 2 : Anode
- 3: Cathode
- 4 : N.C.
- 5 : GND
- 6: VO (Output)
- 7 : Vo
- 8: V_{CC}

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Absolute Maximum Ratings (Ta = 25°C)

	Characteristic	Symbol	Rating	Unit	
	Forward current	lF	20	mA	
	Forward current derating (Ta ≥ 70°C)	ΔI _F / ΔTa	-0.36	mA / °C	
LED	Peak transient forward curent	(Note 1)	I _{FPT}	1	А
	Reverse voltage		V _R	5	V
	Junction temperature		Tj	125	°C
	"H"peak output current (P _W ≤ 2.5µs,f ≤ 15kHz)	I _{OPH}	-1.5	Α	
	"L"peak output current (P _W ≤ 2.5µs,f ≤ 15kHz)	(Note 2)	I _{OPL}	+1.5	А
	Output voltage	(Ta ≤ 70°C)	Vo	35	V
	Output voltage	(Ta = 85°C)	۷O	24	V
Detector	Supply voltage	(Ta ≤ 70°C)	V _{CC}	35	V
ă	Supply voltage	(Ta = 85°C)	VCC VCC	24	V
	Output voltage derating (Ta ≥ 70°C)	ΔV _O / ΔTa	-0.73	V / °C	
	Supply voltage derating (Ta ≥ 70°C)	ΔV _{CC} / ΔTa	-0.73	V / °C	
	Junction temperature	Tj	125	°C	
Opera	ating frequency	f	25	kHz	
Opera	ating temperature range	T _{opr}	-20~85	°C	
Stora	ge temperature range	T _{stg}	-55~125	°C	
Lead	soldering temperature (10 s)	T _{sol}	260	°C	
Isolat	ion voltage (AC, 1 min., R.H.≤ 60%)	BVS	2500	Vrms	

- (Note 1) Pulse width $P_W \le 1\mu s$, 300pps
- (Note 2) Exporenential wavefom
- (Note 3) Exporenential waveform, $I_{OPH} \le -1.0A(\le 2.5 \mu s)$, $I_{OPL} \le +1.0A(\le 2.5 \mu s)$
- (Note 4) Device considerd a two terminal device: Pins 1, 2, 3 and 4 shorted together, and pins 5, 6, 7 and 8 shorted together.
- (Note 5) A ceramic capacitor(0.1µF) should be connected from pin 8 to pin 5 to stabilize the operation of the high gain linear amplifier. Failure to provide the bypassing may impair the switching proparty. The total lead length between capacitor and coupler should not exceed 1cm.

Recommended Operating Conditions

Characteristic	Symbol	Min.	Тур.	Max.		Unit
Input current, on	I _{F(ON)}	7	8	10		mA
Input voltage, off	V _{F(OFF)}	0	_	0.8		V
Supply voltage	V _{CC}	15	_	30	20	V
Peak output current	I _{OPH} /I _{OPL}	_	_	±0.5		Α
Operating temperature	T _{opr}	-20	25	70	85	°C

Electrical Characteristics (Ta = $-20\sim70$ °C, unless otherwise specified)

Characteristic		Symbol	Test Cir– cuit	Test Condition	Min.	Typ.*	Max.	Unit	
Input forward voltage		V _F	_	I _F = 10 mA , Ta = 25°C		1.6	1.8	٧	
Temperature coefficient of forward voltage		ΔV _F / ΔTa	_	I _F = 10 mA	_	-2.0	_	mV / °C	
Input reverse current		I _R	_	V _R = 5V, Ta = 25°C		_	10	μА	
Input capacitance		C _T	_	V = 0 , f = 1MHz , Ta = 25°C	_	45	250	pF	
Output current	"H" level	I _{OPH}	3	$V_{CC} = 30V$ $I_F = 10 \text{ mA}$ $V_{8-6} = 4V$	-0.5	-1.5	_	Α	
Output current	"L" level	I _{OPL}	2	$\begin{array}{ c c c }\hline (*1) & & & \\ I_F = 0 & & \\ V_{6-5} = 2.5V & & \\ \end{array}$	0.5	2	_		
Output voltage	"H" level	V _{OH}	4	V_{CC1} = +15V, V_{EE1} = -15V R_L = 200 Ω , I_F = 5mA	11	12.8	_	- V	
	"L" level	V _{OL}	5	V_{CC1} = +15V, V_{EE1} = -15V R_L = 200 Ω , V_F = 0.8V	_	-14.2	-12.5		
	"H" level	Іссн	_	V _{CC} = 30V, I _F = 10mA Ta = 25°C	_		_		
Supply current				V _{CC} = 30V, I _F = 10mA			mA		
Зирріу сипені	"L" level	I _{CCL}	_	V _{CC} = 30V, I _F = 0mA Ta = 25°C	_	7.5	_		
				V _{CC} = 30V, I _F = 0mA	_	_	11		
Threshold input current	"Output L→H"	I _{FLH}	_	V_{CC1} = +15V, V_{EE1} = -15V R_L = 200 Ω , V_O > 0V	_	1.2	5	mA	
Threshold input voltage	"Output H→L"	I _{FHL}	_	V_{CC1} = +15V, V_{EE1} = -15V R_L = 200 Ω , V_O < 0V	0.8	_	_	V	
Supply voltage		V _{CC}	_		10	_	35	V	
Capacitance (input–output)		CS		V _S = 0 , f = 1MHz Ta = 25°C	_	1.0	2.0	pF	
Resistance(input-output)		R _S	_	V _S = 500V , Ta = 25°C R.H.≤ 60%	1×10 ¹²	10 ¹⁴	_	Ω	

^{*} All typical values are at Ta = 25°C (*1): Duration of I_O time \leq 50 μ s

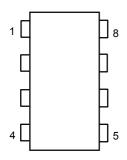
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Switching Characteristics (Ta = $-20 \sim 70^{\circ}$ C , unless otherwise specified)

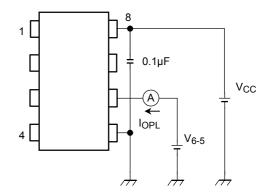
Characteristic		Symbol	Test Cir– cuit	Test Condition	Min.	Typ.*	Max.	Unit
Propagation delay time	L→H	t _{pLH}	6	I _F = 8mA	_	0.15	0.5	
	H→L	t _{pHL}			_	0.15	0.5	
Output rise time		t _r		\dot{V}_{CC1} = +15V, V_{EE1} = -15V R_L = 200 Ω	_	_	_	μs
Output fall time		t _f			_	_	_	
Common mode transient immunity at high level output		C _{MH}	7	V _{CM} = 600V, I _F = 8mA V _{CC} = 30V, Ta = 25°C	-5000	_	-	V / µs
Common mode transient immunity at low level output		C _{ML}	7	V _{CM} = 600V, I _F = 0mA V _{CC} = 30V, Ta = 25°C	5000	_	_	V / µs

^{*} All typical values are at Ta = 25°C

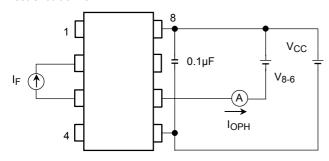
Test Circuit 1:



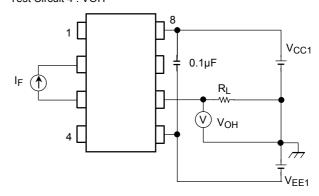
Test Circuit 2: IOPL



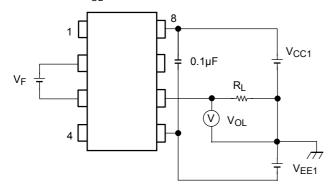
Test Circuit 3: IOPH



Test Circuit 4: VOH

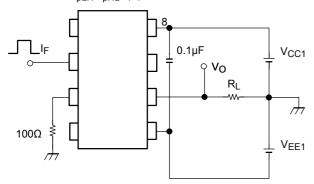


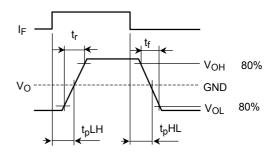
Test Circuit 5 : V_{OL}



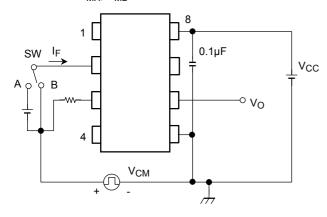
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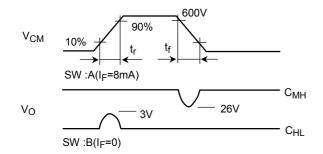
Test Circuit 6: t_{pLH}, t_{pHL}, t_r t_f





Test Circuit 7: C_{MH}, C_{ML}

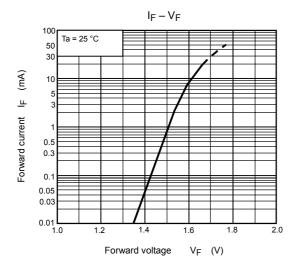


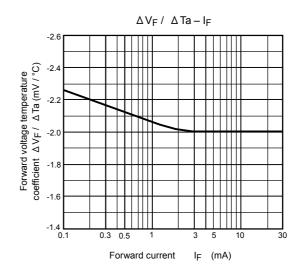


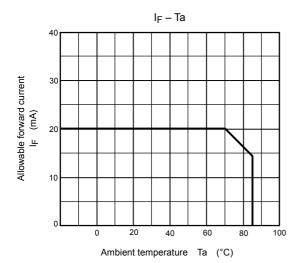
$$C_{ML} = \frac{480 \text{ (V)}}{t_{r \text{ (µs)}}}$$
$$C_{MH} = \frac{480 \text{ (V)}}{t_{f \text{ (µs)}}}$$

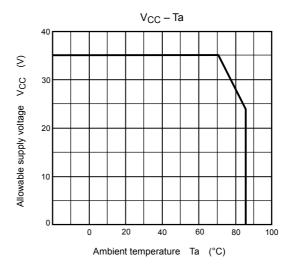
 $C_{ML}(C_{MH})$ is the maximum rate of rise (fall) of the common mode voltage that can be sustained with the output voltage in the low (high) state.

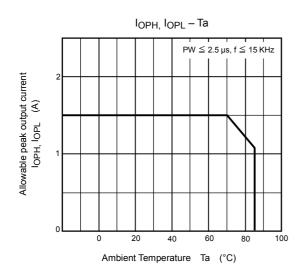
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